

# High Current Prospects for Polarized Electron Sources

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Barrowing liberally from past talks by:

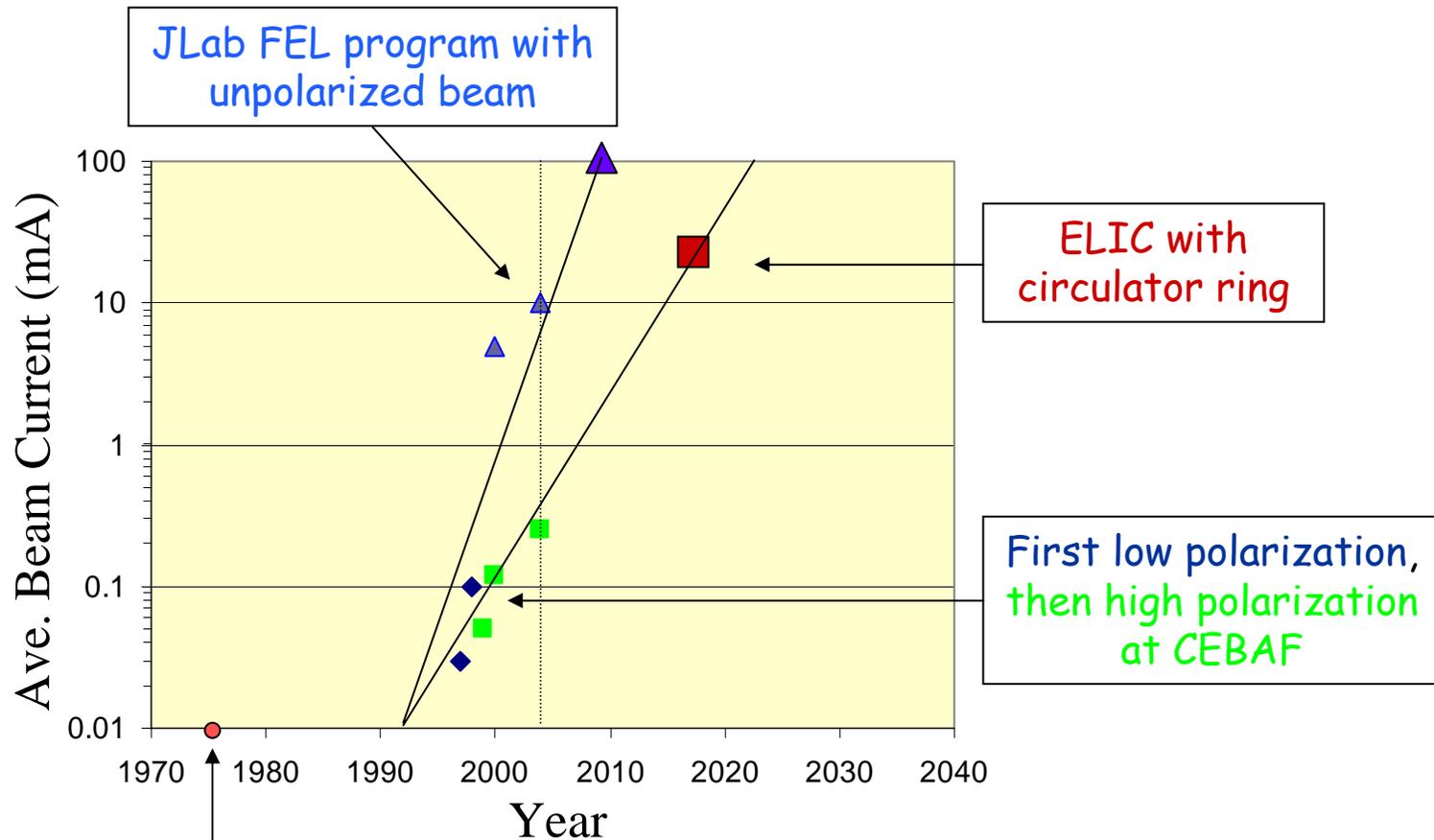
C. Sinclair, "Thoughts on a Polarized Electron Source for a LINAC-Ring EIC"

P. Hartmann, "Polarized Electron LINAC Sources", BNL EIC Workshop, 2000

EIC Accelerator Workshop  
Jefferson Lab  
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# Continuing Trend Towards Higher Average Beam Current



Source requirements for ELIC less demanding with circulator ring. Big difference compared to past talks. Few mA's versus  $\gg 100$  mA of highly polarized beam.



# Gun Issues for New High Current CW Machines

~ 100 mA Unpolarized Beam for Light Sources  
( e.g., JLab FELs and Cornell ERL) and Cooler Rings

- Unpolarized beam so bulk GaAs OK
- Expect 10% QE at 532 nm;
  - 4.3 mA/W/%QE
  - ~ 6 W provides 1/e operation at 100 mA
- 10 W commercial doubled Nd:YAG lasers with rep rates to 100 MHz are available.
- Higher rep rates requires laser R&D (SESAMs, Ti-Saps)
- Lifetime? Probably wise to improve vacuum (more later)
- Charge Limit? No (bunch charge < 1 nC). Also, not a big problem with heavily doped bulk GaAs and high QE.
- Gun HV ~ 500 kV to mitigate emittance growth.
  - Must limit field emission.



# Gun Issues for New Pulsed Machines

## Electron-Positron Colliders; NLC, JLC, CLIC, TESLA

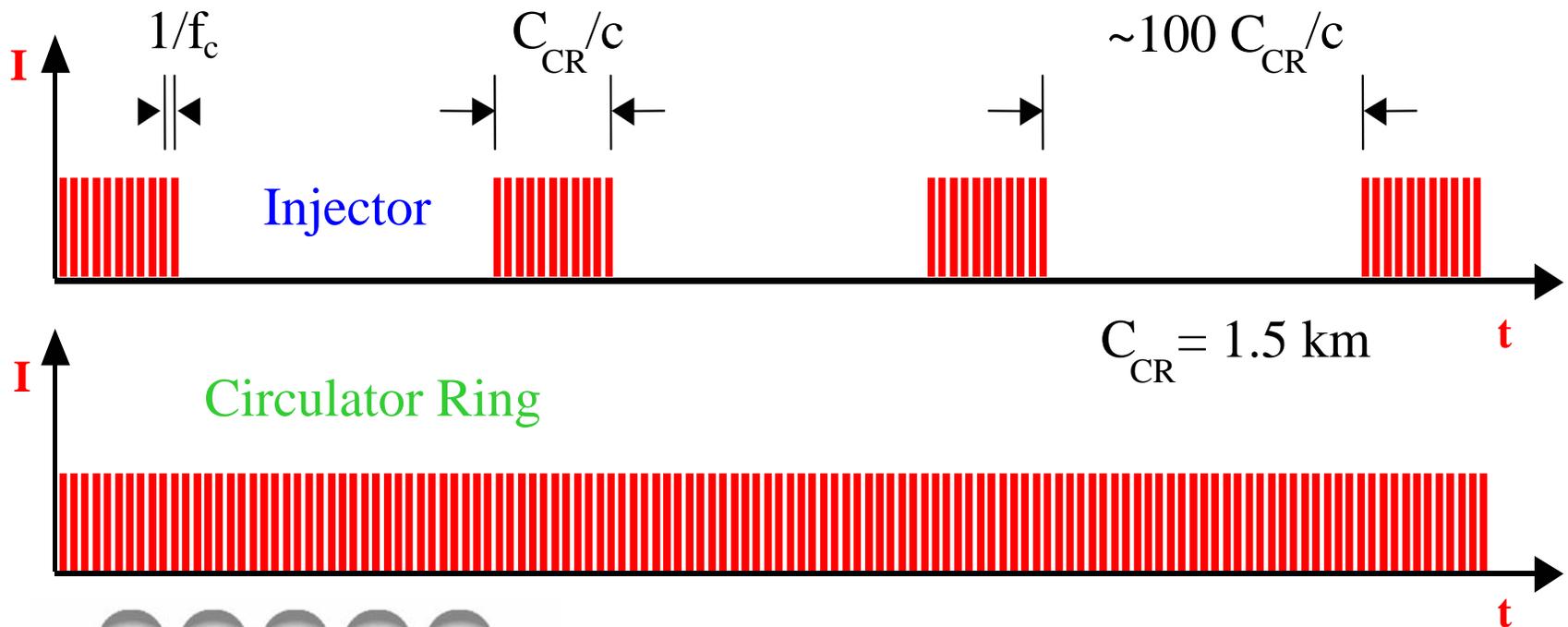
- Polarization 80%, Photocathode QE only 0.1 to 1%.
- Very high peak current but low average current ( $< 30\mu\text{A}$ ), so low QE not a problem.
- Expect good lifetime with present vacuum technology.
- Charge Limit? Yes, at nC bunch charge. Heavily doped photocathode surface helps (but tough to keep heavily doped surface after repeated activations).
- Peculiar laser pulse structures; microstructure within macrostructure. Large micropulse width and low rep rate for TESLA. R&D required.



# ELIC e-Beam Specifications

Typical parameters;

- Ave injector gun current 2.5 mA (and then 25 mA)
- Micropulse bunch charge 1.6 nC
- Micropulse rep rate 150 MHz (and then 1.5 GHz)
- Macropulse rep rate  $\sim 2$  kHz, 0.5 ms duration.



# Gun Issues for ELIC

- Need 80% polarized e-beam.
- Use SVT superlattice photocathode. 1% QE at 780 nm;
  - 6.3 mA/W/%QE
  - ~ 1 W provides 1/e operation at 2.5 mA
- Commercial Ti-Sapp lasers with CW rep rates to 500 MHz provide 0.5 W. Homemade lasers provide ~ 2W.
- Injector micropulse/macropulse time structure demands laser R&D.
- 25 mA operation requires more laser power and/or QE.
- Charge Limit? Yes, at 1.6 nC/bunch and low QE wafers.
- Lifetime? Probably wise to improve vacuum (more later)
- Gun HV ~ 500 kV to mitigate emittance growth.
  - Must limit field emission.



# Gun Lifetime

- CEBAF enjoys good gun lifetime;
  - ~ 200 C charge lifetime (until QE reaches  $1/e$  of initial value)
  - ~ 10,000 C/cm<sup>2</sup> charge density lifetime (we operate with a ~ 0.5 mm dia. laser spot)
- Gun lifetime dominated by ion backbombardment.
- So it's reasonable to assume lifetime proportional to current density.
- Use a large laser spot to drive ELIC gun. This keeps charge density small. **Expect to enjoy the same charge density lifetime, despite higher ave. current operation, with existing vacuum technology.**



# Gun Lifetime cont.

## Lifetime Estimate;

- Use 1 cm diameter laser spot at photocathode.
- At 2.5 mA gun current, we deliver 9 C/hour, 216 C/week.
- Charge delivered until QE falls to 1/e of initial value;

$$10,000 \text{ C/cm}^2 * 1 \text{ Wk} / 216 \text{ C} * 3.14(0.5 \text{ cm})^2 = 36 \text{ Wks!}$$

3.6 Weeks lifetime at 25 mA.

- Need to test the scalability of charge lifetime with laser spot diameter. Measure charge lifetime versus laser spot diameter in lab.



# Improving Gun Vacuum

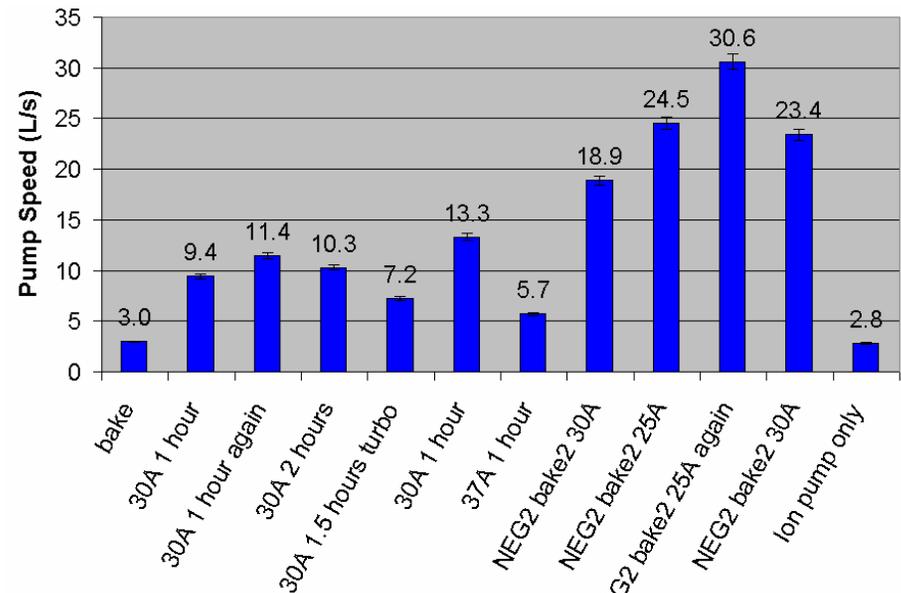
CEBAF gun vacuum  $\sim 1e10-11$  Torr. Reasonable to expect order of magnitude improvement.

$$\text{Ultimate Pressure} = \frac{\text{Outgassing Rate} \times \text{Surface Area}}{\text{Pump Speed}}$$

We need; Smaller outgassing rate, Less surface area, More pump speed.



Work by Adderley, Stutzman



# Laser Power and Max QE

- Present state of the art;
  - QE = 1% at ~ 80% polarization (SVT superlattice photocathode)
  - TimeBandwidth SESAM modelocked Ti-Sapphire laser with rep rates to 500 MHz and ave. power ~ 500 mW
  - "Homemade" modelocked Ti-Sapphire laser with rep rates to ~ 3 GHz and ave. power ~ 2 W (C. Hovater and M. Poelker, Nucl. Instr. And Meth. A418, 280 (1998)).
- We should be able to deliver 12.6 mA today! Albeit with a CW pulse structure.



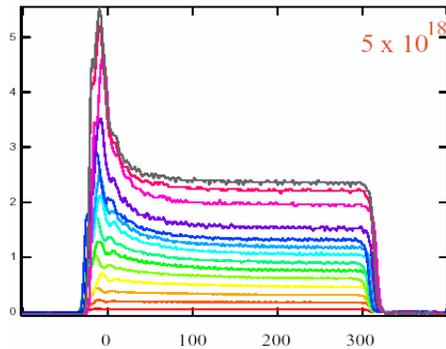
# Laser Power and Max QE Problems

- My 2 W laser does not meet ELIC pulse structure requirements.
- How to generate required peak power? 100 W peak power to meet 2.5 mA spec. Tough job!
- High power diode lasers might create macropulse but can't turn ON/OFF fast enough to create micropulses. Maybe use rf cavities to create microstructure? ([M. Farkhondeh, this workshop](#))
- Can we build Q-switched, modelocked Ti-Sapphire laser with  $\sim 2$  kHz macropulse structure and 1 W ave. power?

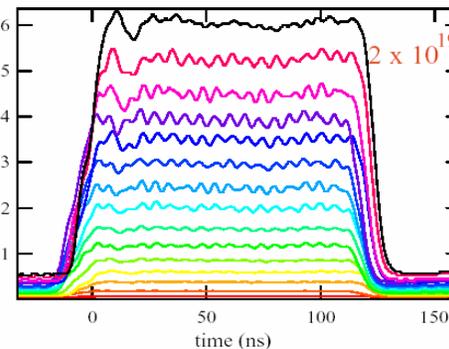


# Charge Limit Problems

- Charge accumulates at surface and opposes photoemission. QE drops with increasing laser power. Problem at high bunch charge ( $\sim$  nC).
- What to do?
  - Use high dopant density at surface. But dopant diffuses after repeated heat and activation cycles.
  - Use big laser spot to minimize charge density.



$5 \times 10^{18} / \text{cm}^3$



$2 \times 10^{19} / \text{cm}^3$

doping density

T. Maruyama et al., SPIN  
2002 Proceedings, Workshop  
on Polarized Electrons  
Sources and Polarimeters,  
MIT Bates



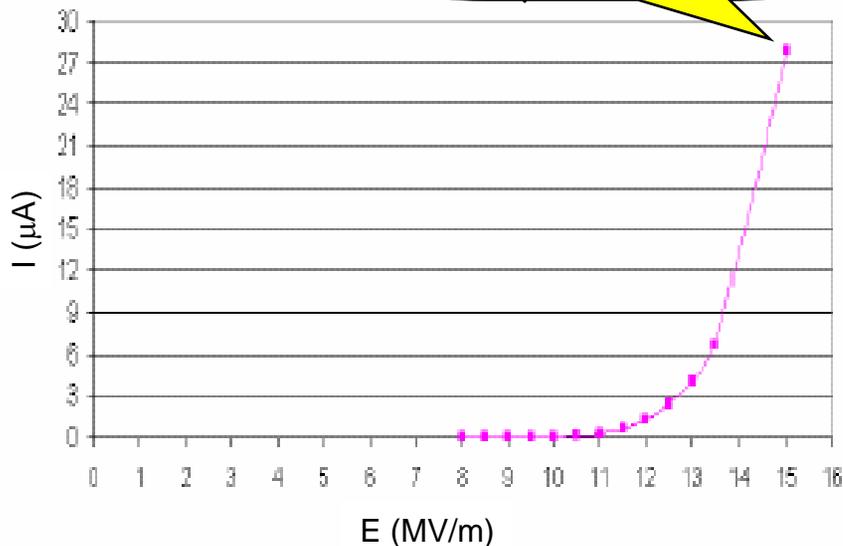
# Suppressing Field Emission

(necessary to preserve vacuum and prolong operating lifetime of gun. Easy at 100 kV. A bit more difficult at 500 kV)

Studies on flat SS electrodes show that field emission is greatly reduced by Plasma Source Ion Implantation

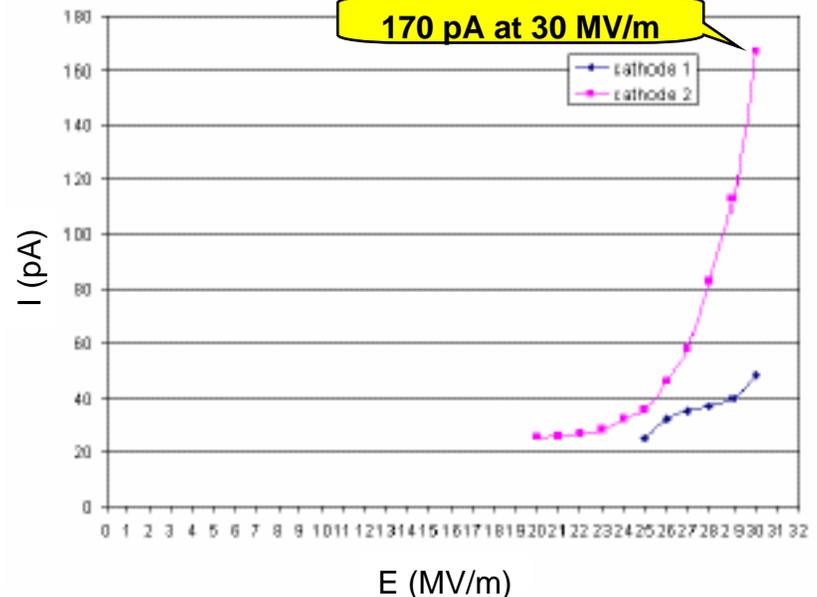
Field emission from a 1  $\mu\text{m}$  finish bare SS electrode

28  $\mu\text{A}$  at 15 MV/m



Field emission from a 9  $\mu\text{m}$  finish SS electrode treated by PSII

170 pA at 30 MV/m



From C. K. Sinclair, H. F. Dylla, T. L. Siggins, D. Manos, L. Wu, and T. J. Venhaus, Proceedings of the 2001 Particle Accelerator Conference, Chicago, IL, p.610.



# Summary

- As with past speakers, I've assumed emittance is not an issue.
- Circulator Ring reduces demands on photogun. Good news! Ave. gun current between 2.5 and 25 mA instead of 250 and 2500 mA. As a result, expect good lifetime with existing vacuum technology (although vacuum improvements wouldn't hurt...).
- We still have significant laser issues. Thanks to the circulator ring, we have more modest average power requirements but we still have very high peak power requirements. It's a tough job to create necessary laser pulse structure.
- Alternate circulator filling schemes?



# Summary cont.

- Chalcopyrite photocathodes are still worth studying. High polarization and QE comparable to bulk GaAs (in theory). Samples from A. Rockett of UofI in-house.
- Charge limit problems? Work of Nagoya, SLAC groups suggest there will be problems. Need to study.
- Modest engineering challenges to be overcome; photocathode cooling, load-lock gun design, HV ceramic issues, cryopumping?, vacuum chamber diffusion coatings to limit outgassing, ...
- Jlab Source Group excited about conducting high current ( $\sim$  mA), high polarization tests. We have tools in house; SVT superlattice photocathodes, 2 W homemade modelocked Ti-Sapp laser, 100 kV loadlocked gun and beamline.

